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# CGD982LC

# 1 GHz, 23 dB gain GaAs low current power doubler

Rev. 1 — 10 March 2014

**Product data sheet** 

# 1. Product profile

### 1.1 General description

Hybrid amplifier module in a SOT115AE package, operating at a supply voltage of 24 V Direct Current (DC), employing Heterojunction Field Effect Transistor (HFET) GaAs dies.

#### 1.2 Features and benefits

- Low power consumption
- Excellent linearity
- Optimized for PAL D loading
- Extremely low noise
- Excellent return loss properties
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)
- Gain compensation over temperature
- Rugged construction
- Unconditionally stable
- Thermally optimized design
- Adjustable supply current

## 1.3 Applications

 CATV systems operating in the 40 MHz to 1 GHz frequency range using PAL D channel conditions.

#### 1.4 Quick reference data

Table 1. Quick reference data

Bandwidth 40 MHz to 1003 MHz;  $V_B = 24 \text{ V (DC)}$ ;  $Z_S = Z_L = 75 \Omega$ ;  $T_{mb} = 35 \text{ °C}$ ; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Gp	power gain	f = 50 MHz		20.5	21.5	22.5	dB
		f = 1003 MHz		22	23	24	dB
СТВ	composite triple beat	V <sub>o</sub> = 48 dBmV at 862 MHz	[1][2]	-	-65	-59	dBc
CSO	composite second-order distortion	V <sub>o</sub> = 48 dBmV at 862 MHz	[1][2]	-	-70	-60	dBc
I <sub>tot</sub>	total current	pin 4 not connected	[3]	345	365	385	mA
		pin 4 connected to ground	[3]	-	315	-	mA

<sup>[1] 98</sup> PAL D channels with 8 MHz bandwidth per channel; [f = 47 MHz to 862 MHz]; flat  $V_0$  till 862 MHz.

- [2] Pin 4 not connected.
- [3] Direct Current (DC).



### 1 GHz, 23 dB gain GaAs low current power doubler

# 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	input		<b>~</b> 1 1
2, 3	common	1 5 7 9	1 4 5 9
4	I <sub>CC</sub> adjust [1]		
5	+V <sub>B</sub>		2 3 7 8
7, 8	common		aaa-011041
9	output		

<sup>[1]</sup> The total supply current can be adjusted by pin 4. Grounding of pin 4 gives the lowest supply current while floating of pin 4 gives the maximum supply current.

# 3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
CGD982LC	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 × 6-32 UNC and 2 extra horizontal mounting holes; 8 gold-plated in-line leads	SOT115AE			

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_B$	supply voltage		-	30	٧
$V_{i(RF)}$	RF input voltage	single tone	-	75	dBmV
l <sub>l</sub>	input current	on I <sub>CC</sub> adjust (pin 4)	-10	0	mA
T <sub>stg</sub>	storage temperature		-40	+100	°C
T <sub>mb</sub>	mounting base temperature		-20	+100	°C

## 1 GHz, 23 dB gain GaAs low current power doubler

## 5. Characteristics

Table 5. Characteristics

Bandwidth 40 MHz to 1003 MHz;  $V_B = 24 \text{ V (DC)}$ ;  $Z_S = Z_L = 75 \Omega$ ;  $T_{mb} = 35 \text{ °C}$ ; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
G <sub>p</sub>	power gain	f = 50 MHz		20.5	21.5	22.5	dB
		f = 1003 MHz		22	23	24	dB
SL <sub>sl</sub>	slope straight line	f = 40 MHz to 1003 MHz	[1]	0.5	-	2	dB
FL	flatness of frequency response	f = 40 MHz to 1003 MHz	[2]	-	-	0.8	dB
RLin	input return loss	f = 40 MHz to 160 MHz		20	-	-	dB
		f = 160 MHz to 320 MHz		20	-	-	dB
		f = 320 MHz to 640 MHz		19	-	-	dB
		f = 640 MHz to 870 MHz		17	-	-	dB
		f = 870 MHz to 1003 MHz		15	-	-	dB
RL <sub>out</sub>	output return loss	f = 40 MHz to 160 MHz		20	-	-	dB
		f = 160 MHz to 320 MHz		20	-	-	dB
		f = 320 MHz to 640 MHz		19	-	-	dB
		f = 640 MHz to 870 MHz		17	-	-	dB
		f = 870 MHz to 1003 MHz		16	-	-	dB
NF	noise figure	f = 50 MHz		-	5.2	6.0	dB
		f = 1003 MHz		-	5.7	6.5	dB
Pin 4 not	connected						
I <sub>tot</sub>	total current		[3]	345	365	385	mA
98 PAL D	channels			·			
СТВ	composite triple beat	V <sub>o</sub> = 48 dBmV at 862 MHz	[4]	-	-65	-59	dBc
CSO	composite second-order distortion	V <sub>o</sub> = 48 dBmV at 862 MHz	[4]	-	-70	-60	dBc
Xmod	cross modulation	V <sub>o</sub> = 48 dBmV at 862 MHz	[4][5]	-	-60	-	dB
59 PAL D	channels + 75 digital channels			·			
СТВ	composite triple beat	V <sub>o</sub> = 58.5 dBmV at 1003 MHz	[6]	-	-72	-	dBc
CSO	composite second-order distortion	V <sub>o</sub> = 58.5 dBmV at 1003 MHz	[6]	-	-75	-	dBc
Xmod	cross modulation	V <sub>o</sub> = 58.5 dBmV at 1003 MHz	[5][6]	-	-67	-	dB
CCN	carrier-to-composite noise	V <sub>o</sub> = 58.5 dBmV at 1003 MHz	[6]	-	62	-	dBc
		· · · · · · · · · · · · · · · · · · ·				_	_

## 1 GHz, 23 dB gain GaAs low current power doubler

 Table 5.
 Characteristics ...continued

Bandwidth 40 MHz to 1003 MHz;  $V_B = 24 \text{ V (DC)}$ ;  $Z_S = Z_L = 75 \Omega$ ;  $T_{mb} = 35 \degree C$ ; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Pin 4 con	nected to ground					
I <sub>tot</sub>	total current	[3]	-	315	-	mA
98 PAL D	channels					
СТВ	composite triple beat	$V_0 = 48 \text{ dBmV at } 862 \text{ MHz}$	-	-58	-	dBc
CSO	composite second-order distortion	$V_0 = 48 \text{ dBmV at } 862 \text{ MHz}$	-	-69	-	dBc
59 PAL D	channels + 75 digital channels					
СТВ	composite triple beat	$V_0 = 58.5 \text{ dBmV at } 1003 \text{ MHz}$ [6]	-	-61	-	dBc
CSO	composite second-order distortion	$V_0 = 58.5 \text{ dBmV at } 1003 \text{ MHz}$ [6]	-	-74	-	dBc
CCN	carrier-to-composite noise	$V_0 = 58.5 \text{ dBmV at } 1003 \text{ MHz}$ [6]	-	55	-	dBc

- [1]  $G_p$  at 1003 MHz minus  $G_p$  at 40 MHz.
- [2] Flatness is defined as peak deviation to straight line.
- [3] Direct Current (DC).
- [4] 98 PAL D channels with 8 MHz bandwidth per channel; [f = 47 MHz to 862 MHz]; flat  $V_0$  till 862 MHz.
- [5] Measured at 55.25 MHz.
- [6] 59 PAL D channels [f = 49.75 MHz to 543.25 MHz] + 75 digital channels [f = 555.25 MHz to 1003 MHz] (-10 dB offset); 13.5 dB tilt extrapolated to 1003 MHz.

### 1 GHz, 23 dB gain GaAs low current power doubler

## 6. Package outline

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 8 gold-plated in-line leads

SOT115AE

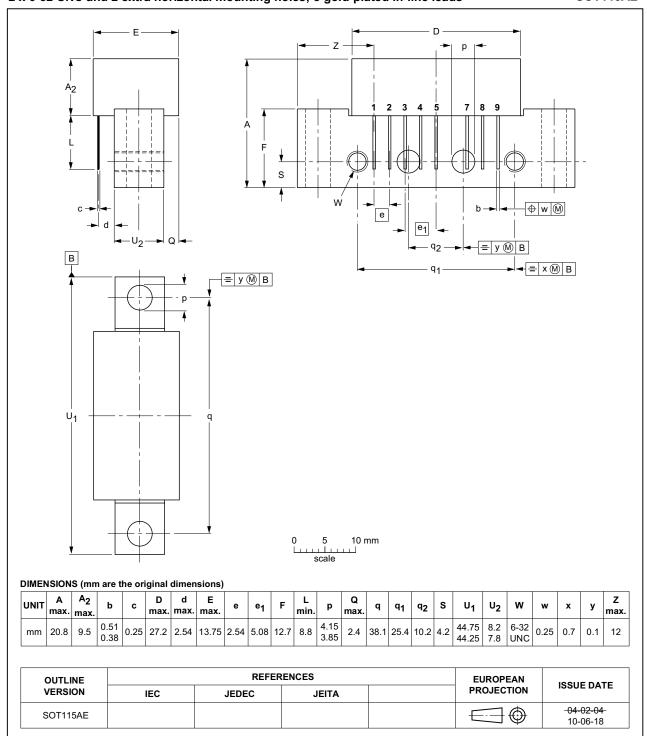


Fig 1. Package outline SOT115AE

## 1 GHz, 23 dB gain GaAs low current power doubler

## 7. Abbreviations

Table 6. Abbreviations

Acronym	Description
CATV	Community Antenna TeleVision
ESD	ElectroStatic Discharge
GaAs	Gallium-Arsenide
PAL D	Phase Alternate Line standard D
UNC	UNified Coarse

# 8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
CGD982LC v.1	20140310	Product data sheet	-	-

#### 1 GHz, 23 dB gain GaAs low current power doubler

## 9. Legal information

#### 9.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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### 1 GHz, 23 dB gain GaAs low current power doubler

# 11. Contents

1	Product profile
1.1	General description 1
1.2	Features and benefits
1.3	Applications
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Limiting values 2
5	Characteristics 3
6	Package outline 5
7	Abbreviations 6
8	Revision history 6
9	Legal information 7
9.1	Data sheet status 7
9.2	Definitions 7
9.3	Disclaimers
9.4	Trademarks 8
10	Contact information 8
11	Contents

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